

# FLEX PHOTOIMAGE MASK NPR-80/ID60

- Alkaline Developable Photoimagable Solder Mask for Flex PCBs -

## **Product system**

Main resin:

NPR-80 /ID60 (Green color)

Hardener:

HARDENER PF-10/ID60

## Nippon Polytech Corp.



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#### 1. General

**FLEX PHOTOIMAGE MASK "NPR-80/ID60"** is the flame retarded solder resist with the halogen compound. The features of this product are flame retardancy, excellent reliability and low tackiness. It is alkaline developable two component ink coated the screen printing. It is developed for a high density flexible printed circuit boards (FPCs).

#### 2. Special Features

- UL 94 V-0.
- Low tackiness, the contact exposure is possible.
- Good bending resistance, real plane flexible circuit is always expectable.
- Stable in electroless Ni/Au plating operation, good plating results is always expectable.
- Excellent characteristic of PCT, HHBT.
- By the way of photoimaging, a superior fine line, fine pitch resolution is expectable.

#### 3. Direction to use

## i) Preparationof the ink

Mix the main resins "NPR-80/ID60" with the specified hardener "PF-10/ID60" by the instructed ratio, and stir thoroughly before use. Hold for at least 30 minutes before put into application.

\* Use as supplied, without dilution as possible. Dilution might cause a drop of coated-film thickness on the edge of the circuit. Employ the specified thinner SOLVENT #8500 for the purpose, if a dilution is absolutely required.

#### Specifications of the ink

	NPR-80/ ID60	HARDENER PF-10/ ID60	
Packaging size	720 g	280 g	
Ratio of Main Resins / Hardener	100 g / 39 g		
Form	Green - colored paste	Pale brown - colored paste	
Flash point (sealed cup, Seta method)	82 deg. C	72 deg. C	
Specific Gravity (25 deg. C)	1.2	1.2	
Antifoaming agent	Silicon type (Silicon polymer)		

#### FLEX PHOTOIMAGE MASK NPR-80/ID60

Viscosity of mixture	200∼240 dPa•s	
(25 deg. C, Viscotester VT-04, No.2 rotor)	200 240 di a 3	
Thixotropic Index of mixture	16.20	
(25 deg. C, Brookfield HBT)	1.6~2.0	
Solid content of mixture	about 77 wt%	
(at 130 deg. C for 1hour in a box oven)		
Shelf life (Store at 25 deg. C)	about 90 days	
Pot life (Store at 25 deg. C	about 3 days	
Specified thinner for NPR-80 series	Solvent #8500 (made by Nippon Polytech Corp.)	

ii) Coating	Screen printing application is recommended as for the coating method. A 100 to				
	150 meshes polyester-based screen is recommended.				
	Thickness of solder mask after final curing is recommended 15 to 25 $\mu m$ on the				
	circuit. In case the film thickness is thick excessively, the tackiness, flexibility and				
	developability might fall off.				
iii) Holding	Hold in a clean area for 10 to 30 minutes at room temperature to antifoam the				
	coating ink.				
iv) Drying	[Recommendable drying conditions is as follows]				
	70 deg. C, 30-60 minutes or 75 deg. C, 30-45 minutes or 80 deg. C, 30minutes				
	* The limitations of drying conditions are at 70 deg. C for 75 minutes, 75 deg. C for				
	60 minutes, 80 deg. C for 45 minutes. Do not exceed the said limitation, which might				
	cause a poor developability of coated-film itself.				
v) Cooling	Hold in a cool area, or use a cooling instrument, to cool down the substrate to the				
	room temperature.				



vi) Exposure	[Recommendable exposure co	onditions is as follows]			
	8 to 10 steps of 21steps tab	let <sup>3)</sup> on Cu film is recommended for exposure purpose.			
	The exposure energy is 400 to 600 mJ/cm <sup>2</sup> at scattered light with 7kw metal halide				
	lamp.				
	Do not be short of exposure	energy, which might cause the reliability of cured-film			
	itself. In case of excess expos	sure energy, the halation might cause.			
	The steps are different by the	ne preparation condition of test pieces. The steps were			
	obtained by doing the conditi	ons of Clause 14.			
	3) 21steps tablet; Photec 21	step density tablet made by Hitachi Chemical Co., Ltd.			
vii) Holding	Hold in a clean area for 10	to 30 minutes at room temperature to become stable			
	the photosensitivity.				
viii) Developing	[Recommendable developing conditions is as follows]				
	Solution;	1.0 wt% - Na <sub>2</sub> CO <sub>3</sub> aqueous solution			
	Solution temperature;	30 deg. C			
	Spray pressure;	0.1 to 0.2 MPa			
	Developing time; 60 to 90 seconds				
	Do not exceed the stated limitation, which might cause the poor flexibility and the				
	reliability of cured-film itself.				
ix) Rinsing	[Recommendable rinsing con	ditions is as follows]			
	Solution;	City water and ion exchanged water			
	Rinsing process;	1 <sup>st</sup> step- City wate <u>r</u> , 2 <sup>nd</sup> step – ion exchanged water			
	Solution temperature;	30 deg. C			
	Spray pressure;	0.1 to 0.2 MPa			
	Rinsing time;	60 to 90 seconds			
	In the case that the rinsing is	not sufficient, the flexibility and reliability of the cured			
	film might fall off. Wash it sufficiently by using city water and ion exchanged water.				
x) Thermal curing	Perform the curing in 150 de	eg. C for 30 to 60 minutes in a box oven.			
	* Post-cure; Use UV conve	eyer, in case of plating			
	į				



4. Pot Life						
Time after mix	0.5 hours	1 day	2 days	3 days	4 days	5 days
Viscosity 4)	210	220	240	240	240	250
(dPa·s, 25 deg. C)	210	230	240	240	240	250
drying conditions	Developability					
80 deg. C- 30 minutes	No residue	No residue	No residue	No residue	No residue	No residue
- 45 minutes	No residue	No residue	No residue	No residue	No residue	No residue
- 60 minutes	No residue	No residue	No residue	No residue	Residue	Residue
- 75 minutes	Residue	Residue	Residue	Residue	Residue	Residue
- 90 minutes	Residue	Residue	Residue	Residue	Residue	Residue

<sup>4) 25</sup> deg. C, Viscotester VT-04, No.2 rotor

5. Pre-drying condition vs. Developability						
Pre-dry conditions	70deg. C	75deg. C	80deg. C	85deg. C	90deg. C	
30 minutes	No residue	No residue	No residue	No residue	Residue	
45 minutes	No residue	No residue	No residue	Residue	Residue	
60 minutes	No residue	No residue	No residue	Residue	Residue	
75 minutes	No residue	No residue	Residue	Residue	Residue	
90 minutes	No residue	Residue	Residue	Residue	Residue	

6. Developability after coating 5)					
Pre-dry conditions	Right after coating	1 day	2 days	3 days	
80deg. C- 30 minutes	No residue	No residue	No residue	No residue	
- 45 minutes	No residue	No residue	No residue	Residue	
- 60 minutes	No residue	No residue	Residue	Residue	
- 75 minutes	Residue	Residue	Residue	Residue	
- 90 minutes	Residue	Residue	Residue	Residue	

<sup>5)</sup> Store in a clean area at room temperature after UV exposure.



#### 7. Physical Properties

Test items		Typical value	Reference data		
		8 – 9	Hitachi 21 step tablet 3)		
Photosensi	tivity on	rolle	ed Cu substrate	9 – 10	Stouffer 21 step guide <sup>6)</sup>
				26 – 31	Stouffer 41 step guide <sup>7)</sup>
Resolution	(µm) on	roll	ed Cu substrate	40 / 40	Hitachi Photec G2 test pattern 8)
(Line	/ Space)			50 / 300	Hitachi Photec No.1 test pattern 9)
Pencil hard	lnoss on	ro11a	d Connor	5H	JIS K 5600, cohesive fracture
renen nare	illess oil	ione	и Соррег	2Н	JIS K 5600, plastic deformation
Adhesive s	trength	trength Cross-cut test		Class 0	JIS K 5600, Tape peeling
on rolled C	Copper	Ch	ecker flag type	Pass	TM 2.4.28.1 of IPC-TM-650
Heat sold	lering r	esist	ance on rolled	Pass 2 cycles	RMA flux applied,
Copper					260 deg. C, 5 seconds
Flexibility	on PI fili	m (K	Capton 100H)	Pass	Bending at diameter of 0.2mm
Water abso	orption (%	6)		No data	23 deg. C, 24 H, dipping in H <sub>2</sub> O
(film thick	ness; abo	ut 6	0 μm)	No data	85 deg. C, 85 %Rh, 4 H
Contact an	gle		H <sub>2</sub> O	80°	JIS R3257 - Sessile drop method
Tg (deg. C	)			70	
	Before	Tg	(10 to 40 deg. C)	7 x 10 <sup>-5</sup>	TMA method, Tensile mode
CTE	Immed	iatel	y after Tg	5 x 10 <sup>-3</sup>	Load-5gf, Rate-5 deg. C/min.
(/deg. C) (75 to 81 deg. C) After Tg (110 to 140 deg. C)			Width-3mm, Length-20mm		
		7 x 10 <sup>-5</sup>			
Young's m	odulus (C	GPa)		3.2	1.0 mm/minutes
Tensile stre	ength (M	Pa)		88	10.0 mm/minutes
Breakdown	n elongat	ion (	(%)	2.3	10.0 mm/minutes

<sup>3)</sup> Hitachi 21 step tablet; Photec 21 step density tablet made by Hitachi Chemical Co., Ltd.

- 8) Resolution; Photec Test Pattern No. G2 negative film made by Hitachi Chemical Co., Ltd.
- 9) Resolution; Photec Test Pattern No. 1 negative film made by Hitachi Chemical Co., Ltd.

<sup>6)</sup> Stouffer 21 step guide; Stouffer 21 step sensitivity guide made by Stouffer Graphic Arts Equipment Co.

<sup>7)</sup> Stouffer 41 step guide; Transparent step wedge 41 steps by Stouffer Graphic Arts Equipment Co.



8.	$\mathbf{F}$	lame	retar	dancy
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Flame retardancy	Cover-coat; 10μm	UL 94 V-0	Cover-coat / <u>EPD</u> / Cover-coat EPD; ESPANEX SC substrate, 25µm
	Cover-coat; 30μm	UL 94 V-0	PI film only. (Nippon Steel Chemical)

9. Resistance to solvent 111					
Boiling water test on Co	u film ;60 minutes	No peel off	Tape peeling test		
Resistance to solvents of	on Cu film				
MEK IPA (2-propanol) Methylene Chloride	;30 minutes ;30 minutes ;10 minutes	No peel off  No peel off a slightly swelling	Tape peeling test after dipping at 23 deg. C		
Resistance to acid/base	solutions on Cu film				
10% - H <sub>2</sub> SO <sub>4</sub> 10% - HCl 5% - NaOH	;30 minutes ;30 minutes ;30 minutes	No peel off No peel off No peel off	Tape peeling test after dipping at 23 deg. C		

<sup>11)</sup> Test pieces; pattern of cover coat; TM 2.4.28.1 of IPC-TM-650, PI-Cu substrate: Upisel-N (PI/Cu= $25/12\mu m$ )



### 10. Resistance of electrolytic / electroless Ni / Au plating process

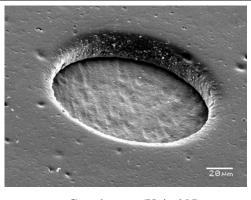
Electroless Ni / Au plating	No penetration & No peel off	NPT process <sup>12)</sup> , Tape peeling test <sup>11)</sup>
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#### 12) Conditions of electroless Ni / Au plating process (NPT process)

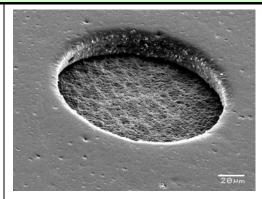
	Process	Solution	Condition
i)	Acid Cleaner	IPC Clean S-135 <sup>13)</sup> 200ml/l	40 deg. C- 4 minutes
ii)	Soft etching	(NH <sub>4</sub> ) <sub>2</sub> S <sub>2</sub> O <sub>8</sub> 100g/l, H <sub>2</sub> SO <sub>4</sub> 10ml/l	23 deg. C- 1 minute
iii)	Smut removal	10% H <sub>2</sub> SO <sub>4</sub>	23 deg. C- 1 minute
iv)	Pre-dipping	3.5% HCl	23 deg. C- 1 minute
v)	Activation	IPC Accera <sup>13)</sup> 200ml/l	23 deg. C- 1 minute
vi)	Electroless Ni	IPC Nicoron GM-SD <sup>13)</sup>	80 deg. C- 20 minutes
	plating	Ni content 5.0g/l, pH 4.6	Thickness of Ni plating - about 3μm
vii)	Acid dipping	3.5% HCl	23 deg. C- 1 minute
viii)	Electroless Au	IM-GOLD IB <sup>14)</sup>	85 deg. C- 20 minutes
	plating	Au content 2.0g/l, pH 4.8	Thickness of Au plating- about 0.08µm
ix)	Washing	Ion-exchanged hot water	80 deg. C- 10 minutes
x)	Drying	Box oven	80 deg. C- 3 minutes

<sup>13)</sup> ICP Clean S-135, ICP Clean 91, ICP Accela, ICP Nicolon GM-SD, and Top Selena; made by Okuno Chemical Industries Co.,Ltd.

#### 11. SEM Photograph



on Cu substrate (Upisel N)



on PI film (Upisel N)

<sup>14)</sup> IM-GOLD IB, Acid strike, Tempereist – EX; made by Japan Pure Chemical Co.,Ltd.



### 12. Electrical Properties

Reliability Test Results			Typical value	Reference data	
Insulation	Line / Space=50 / 50μm		6 x 10 <sup>13</sup>	22.1 CV550/PI	
resistance (ohm)	Line / Space=100 / 100μm		8 x 10 <sup>13</sup>	23 deg. C/55%Rh	
Surface Resistance (ohm)			3 x 10 <sup>13</sup>	TM 2.5.17 of IPC-TM-650	
Volume Resistivity (ohm • cm)			1 x 10 <sup>16</sup>	TM 2.5.17 of IPC-TM-650	
Dielectric Constant (ɛr) 1 MHz		4.11	JIS C6481, 1MHz		
Dielectric Loss Factor (tan δ) 1 MHz		0.029	JIS C6481, 1MHz		
Dielectric Strength			162 kV/mm	TM 2.6.11 of IPC-TM-650	

## 13. Reliability Test Results

HHBT Line / space = 50μm / 50μm (measured resistance condition at test condition)			After 750 hours	No dendrite (> 10 <sup>8</sup> ohm)	85 deg. C/85%Rh/100V DC Electrolytic Cu foil
			After 1000 hours	No dendrite $(>10^8 \text{ ohm})$	
HHBT Line / space = 100μm / 100μm			After 750 hours	No dendrite (> 10 <sup>9</sup> ohm)	85 deg. C/85%Rh/100V DC
(measured resistance condition at test condition)			After 1000 hours	No dendrite (> 10 <sup>9</sup> ohm)	Electrolytic Cu foil
PCT	on Cu substrate			No peel off	121deg. C/0.2MPa/98h Tape peeling; Checker flag type,
PCI	on PI film			No peel off	Test pieces; IPC-TM-650 No. 2.4.28.1
Degradation	in N <sub>2</sub>	5wt%	Loss	307 deg. C	TGA method (40 deg. C/min.)
Temperature 1st di		ssolution	367 deg. C		
	in Air 5wt% Loss		311 deg. C	TGA method (40 deg. C/min.)	
(dry) 1st dissolution		363 deg. C			



		PI: Kapton 100H(25μm), 300H(75μm)	PI; Du Pont-Tray Co., Ltd.
Substrate:		PI-Cu: Upisel N	PI-Cu; Ube Industries. Ltd.
		(Electrolytic Cu foil; PI/Cu=25/12μm	
		Rolled Cu foil; PI/Cu=25/18µm)	
Thickness of solder mask		About 20 μm	
i)	Preparation of the ink	Hold for 30 minutes after mixing	Used a resin mixer, at room temperature
ii)	Coating	100 meshes polyester-based screen	A hand printing
iii)	Holding	23 deg. C- 10 minutes	In the room
iv)	Pre-Drying	80 deg. C - 30 minutes	Box oven
v)	Cooling	23 deg. C - 30 minutes	In the room
vi)	Exposure	500 mJ/cm <sup>2</sup>	7kW, Metalhalide lamp, Scattered light (ORC Manufacturing Co.)
vii)	Holding	23 deg. C - 10 minutes	In the room
viii)	Developing	1%-Na <sub>2</sub> CO <sub>3</sub> aq 30 deg. C	NPT developing process
		- 60 seconds - 0.2 MPa	
ix)	Rinsing:	City water - 30 deg. C	NPT developing process
		- 60 seconds - 0.2 MPa	
x)	Thermal Curing	150 deg. C - 30 minutes	Box oven

#### 15. Green Procurement Survey

NPR-80/ID60 contains 0.2 to 0.3wt% of an organic pigment. The organic pigment comes under Copper and Copper Compound (No. 26, Substance Group No. D01) in List A (Appendix 2-2, Level B) based on Guideline for Standardization of Material Declaration (on July 22, 2003 revision) published by Japan Green Procurement Survey Standardization Initiative (JGPSSI; http://home.jeita.or.jp/eps/).

And this product contains 21 to 25wt% (Br content; 9 to 11wt%) of Tetrabromo-bisphenol A compounds as the brominated flame retardant. The brominated flame retardant comes under Tetrabromo-bisphenol A (unspecified, No. 23, Substance Group No. D08) in List A (Appendix 2-2, Level B).

Also, this product is not using the materials/compounds surveyed Chemical Substance except the organic pigment and the flame retardant in the manufacturing process.



#### 16. Special notice

#### ✓ Handling

The surface hardness of coated film is not hard enough before the thermal curing process. Take it carefully when in handling.

#### ✓ Environment of workshop

- A clean-room under yellow lamp is required.
- Room temperature: 22 to 26 deg. C
- Humidity: 50 to 60 %Rh

#### ✓ Storage

- > Store at a certain cool and dark area. Temperature in 5 to 25 deg. C is recommendable. Avoid direct sunshine and flame.
- ➤ Hold in room temperature for about 1 day before use, if the storage temperature is under 5 deg. C.

#### ✓ Hygienic work Practices

- Local exhaust is required to be set up in workshop.
- Wear on suitable protective clothing when in operation.
- Avoid direct skin contact. Flush with soap and plenty of water thoroughly, if direct contact with skin.
- Flush hands, face and body with soap and plenty of water after handling.

#### ✓ <u>Inflammability</u>

The Principal material "NPR-80/ID60" is the combustible liquid, and the hardener "PF-10/ID60" is the combustible solid. Attention to fire or other sources of ignition.



#### 17. Caution

As to health hazard data, precaution for safe handling/use and others, please refer to the MSDS (Material Safety Data Sheet) of NPR-80/ID60 when in application.

The data mentioned this technical data sheet are based on the results measured NPR-80/ID60 (Green color). In order to get and confirm the sufficient performance, please do the test thoroughly at your end before use.



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